

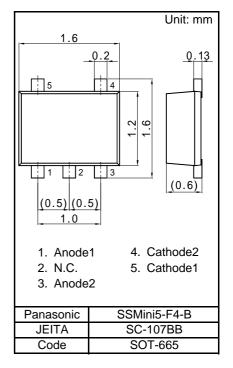
## Schottky Barrier Diode DB5S406K0R

### DB5S406K0R

Silicon epitaxial planar type

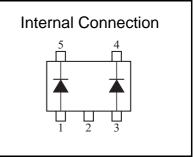
For high speed switching circuits DB4J406K in SSMini5 type package

- Features
- Small reverse current IR
- Short reverse recovery time trr
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 4B
- Basic Part Number : Dual DB2S406 (Parallel)
- Packaging Embossed type (Thermo-compression sealing): 8 000 pcs / reel (standard)



#### ■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit		
Reverse voltage		VR	40	V	
Repetitive peak reverse voltage		VRRM	40	V	
Forward current (Average)	Singie	IF	100	mA	
	Doubie *1		75		
Peak forward current	Singie	IFM	300	mA	
	Doubie *1		225		
Non-repetitive peak	Singie	IFSM	1	A	
forward surge current <sup>*2</sup>	Doubie *1		0.75		
Junction temperature		Tj	125	°C	
Operating ambient temperature		Topr	-40 to +85	°C	
Storage temperature		Tstg	-55 to +125	°C	



Note: \*1 Value of each diode in double used.

\*2 The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)

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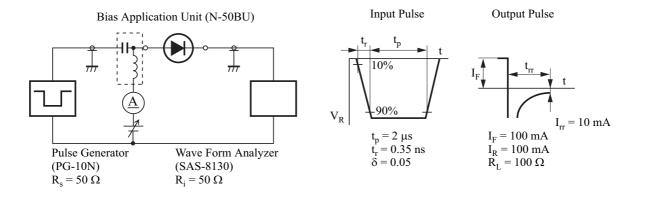
#### Electrical Characteristics $Ta = 25 \circ C \pm 3 \circ C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Forward voltage	VF1	IF = 1 mA			0.35	V	
	VF2	IF = 100 mA			0.60	v	
Reverse current	IR	VR = 40 V			5	μA	
Terminal capacitance	Ct	VR = 10 V, f = 1 MHz		2.2		pF	
Reverse recovery time <sup>*1</sup>	trr	IF = IR = 100 mA, Irr = 10 mA	0.9		ns		
	ui	RL = 100 Ω		0.3		115	

Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on

- 3. the charge of a human body and the leakage of current from the operating equipment.
- Absolute frequency of input and output is 250 MHz.
- 4. \*1 trr test circuit



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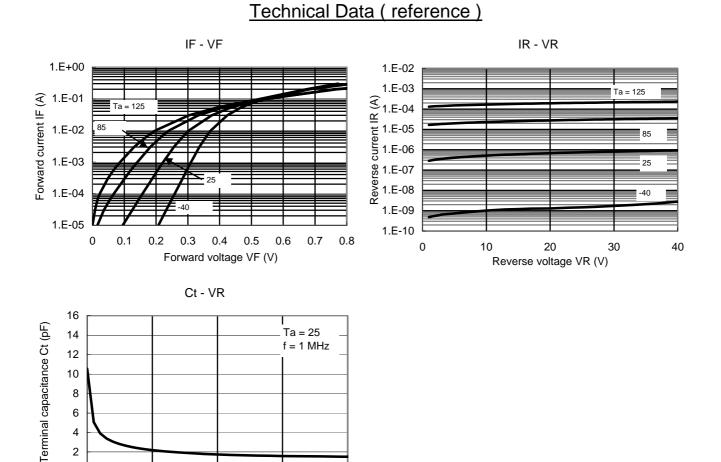
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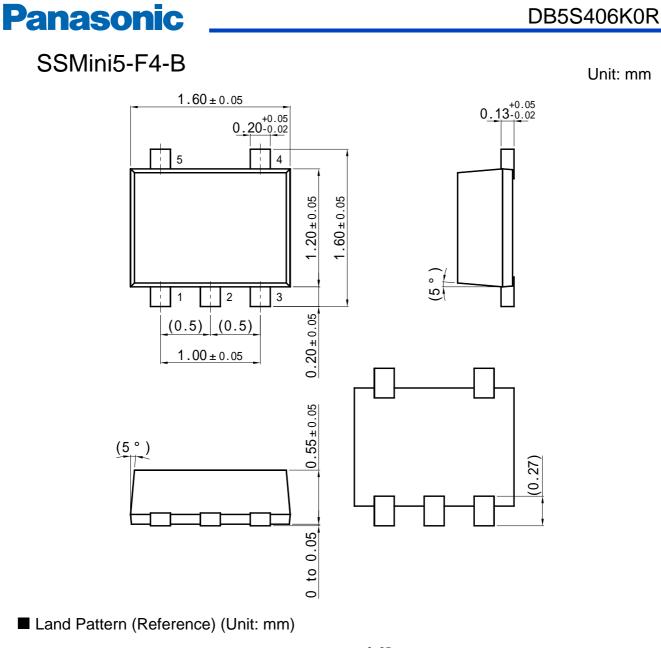
Reverse voltage VR (V)

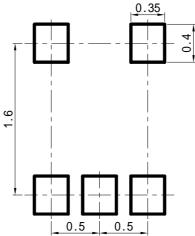
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Schottky Barrier Diode

Established : 2010-04-05 Revised : 2013-12-13

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